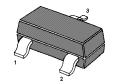
## Silicon Epitaxial Planar Switching Diode

#### **Features**

- AEC-Q101 Qualified
- Small package
- · Low forward voltage
- Fast reverse recovery time
- Small total capacitance
- Halogen and Antimony Free(HAF), RoHS compliant





SOT-23 Plastic Package

### **Applications**

• Ultra high speed switching application

Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Value	Unit	
Maximum Peak Reverse Voltage	V <sub>RM</sub>	85	V	
Reverse Voltage	VR	V <sub>R</sub> 80		
Average Rectified Forward Current	I <sub>F(AV)</sub>	100	mA	
Maximum Peak Forward Current	I <sub>FM</sub>	300	mA	
Non-repetitive Peak Forward Surge Current (10 ms)	IFSM	2	А	
Power Dissipation	P <sub>D</sub>	350	mW	
Junction Temperature	Tj	150	°C	
Storage Temperature Range	T <sub>stg</sub>	- 55 to + 150	°C	

#### **Thermal Characteristics**

Parameter	Symbol	Max.	Unit	
Thermal Resistance from Junction to Ambient 1)	Reja	357	°C/W	

1/4



Dated : 29/03/2024 Rev:01

<sup>&</sup>lt;sup>1)</sup> Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

# 1SS181-AH

## Characteristics at T<sub>a</sub> = 25 ∘C

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R$ = 10 $\mu$ A	$V_{BR(R)}$	80	-	V
Forward Voltage at I <sub>F</sub> = 100 mA	VF	-	1.2	V
Reverse Current at $V_R = 30 \text{ V}$ at $V_R = 80 \text{ V}$	I <sub>R</sub>	- -	0.1 0.5	μΑ
Total Capacitance at $V_R = 0$ , $f = 1$ MHz	Ст	-	4	pF
Reverse Recovery Time at $I_F$ = 10 mA, $I_{rr}$ = 0.1 x $I_R$ , $V_R$ = 6 V, $R_L$ = 100 $\Omega$	t <sub>rr</sub>	-	4	ns



Dated : 29/03/2024 Rev:01

2/4

400 350

50

0

0

25

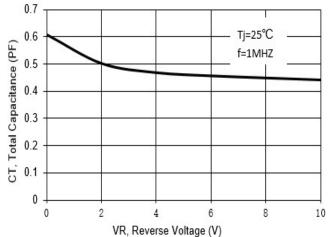
50

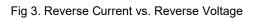
75

### **Electrical Characteristics Curves**

Fig 1. Power Derating Curve

Fig 2. Total Capacitance vs. Reverse Voltage





T<sub>a</sub>, Ambient Temperature(°C)

100

125

150

175

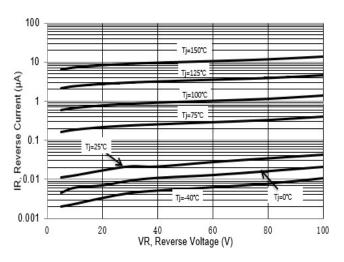
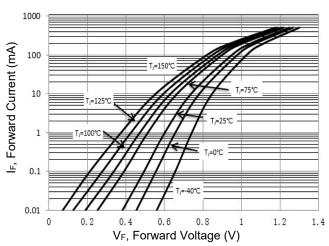


Fig 4. Forward Characteristics

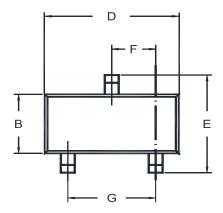


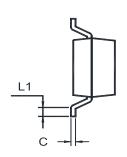


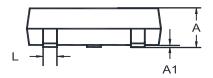
Dated: 29/03/2024 Rev:01

## Package Outline (Dimensions in mm)

**SOT-23** 

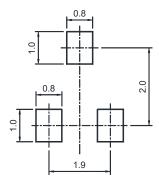






	Unit	Α	A1	В	С	D	Е	F	G	L	L1
	mm	1.20	0.100	1.40	0.19	3.04	2.6	1.02	2.04	0.51	0.2
		0.89	0.013	1.20	0.08	2.80	2.2	0.89	1.78	0.37	MIN

## **Recommended Soldering Footprint**



**Packing information** 

	Tape Width	Pit	tch	Reel	Size	Dan Daal Daaling Overstite		
Package	(mm)	mm	inch	mm	inch	Per Reel Packing Quantity		
SOT-23	-23 8 4 ± 0.1 0.157 ± 0.004		178	7	3,000			

## **Marking information**

"A1" = Part No.

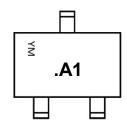
"•" = HAF (Halogen and Antimony Free)

"YM" = Date Code Marking

"Y" = Year

"M" = Month

Font type: Arial



Disclaimer: Our company reserve the right to make modifications, enhancements, improvements, corrections or other changes to improve product design, functions and reliability, anytime without notice. Semtech Electronics Limited makes no warranties, representations or warranties regarding the suitability of its products for any particular purpose, and does not accept any liability arising from the application or use of any product or circuit such as: Apply to medical, military, aircraft, space or life support equipment and expressly waive any and all liability, including but not limited to special, consequential or collateral damage.

4/4



Dated : 29/03/2024 Rev:01